

BP2802EB

High Isolation Voltage DC Input Response Type SSOP Photo Coupler

RoHS
COMPLIANT



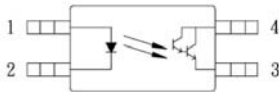
● **Features:**

1. High current transfer ratio (CTR=2000%TYP.@ IF=1 mA, VCE=2V).
2. Small and thin package(4pin SOP, Pin pitch 1.27mm).
3. High isolation voltage between input and output (Viso : 3750Vrms).

● **Application :**

1. Hybrid substrates that require high density mounting.
2. Programmable logic controllers.
3. Communications, Telephone, etc.
3. Measuring instruments.

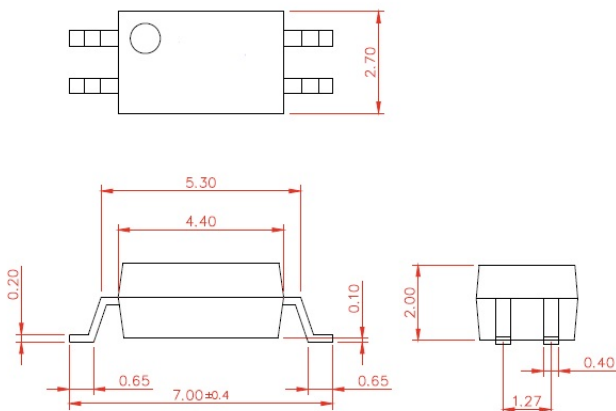
● **Internal Connection Diagram :
Top View**



1. Anode
2. Cathode
3. Emitter
4. Collector

● **Outline Dimensions : (Unit : mm)**

□BP2802EB

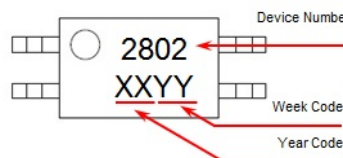


● **Classification table of current transfer ratio is shown below.**

Ta=25°C

| Model No. | CTR Rank | CTR (%) |
|-----------|----------|-----------|
| BP2802EB | E Rank | 200~9000 |

Notes:



TOLERANCE : ±0.2mm

● Absolute Maximum Ratings

Ta=25°C

| Parameter | | Symbol | Rating | Unit |
|---------------------------------|--------------------------------------|--------|-------------|-------|
| Input | Forward current | IF | 50 | mA |
| | Peak forward current(*1) | IFP | 1 | A |
| | Reverse voltage | VR | 6 | V |
| | Power dissipation | PD | 60 | mW |
| | Power dissipation derating | PD/°C | 0.6 | mW/°C |
| Output | Collector-emitter voltage | VCEO | 40 | V |
| | Emitter-collector voltage | VECO | 6 | V |
| | Collector current | IC | 90 | mA |
| | Collector power dissipation | PC | 120 | mW |
| | Collector power dissipation derating | PC/°C | 1.2 | mW/°C |
| Isolation voltage 1 minute(*2) | | Viso | 3750 | Vrms |
| Operating temperature | | Topr | -30 to +115 | °C |
| Storage temperature | | Tstg | -55 to +150 | °C |
| Soldering temperature 10 second | | Tsol | 260 | °C |

*1 PW=100µs, Duty Cycle=1%.

*2 AC voltage for 1minute at T =25°C, RH=60% between input and output.

● Electro-optical Characteristics

Ta=25°C

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------------------------------------|----------|-------------------------|--------------------|------------------|------|------|
| Input | Forward voltage | VF | IF=5mA | - | 1.1 | 1.4 | V |
| | Peak forward voltage | VFP | IFP=0.5A | - | - | 3.0 | V |
| | Reverse current | IR | VR=5V | - | - | 5 | µA |
| | Terminal capacitance | Ct | V=0, f=1MHZ | - | 30 | - | pF |
| Output | Collector dark current | ICEO | VCE=40V, IF=0mA | - | - | 0.4 | µA |
| Transfer characteristics | Current transfer ratio | CTR | IF=1mA, VCE=2V | 200 | - | 9000 | % |
| | Collector-emitter saturation voltage | VCE(sat) | IF=10mA, IC=2mA | - | - | 1.0 | V |
| | Isolation resistance | Riso | DC500V | 5x10 ¹⁰ | 10 ¹¹ | - | Ω |
| | Floating capacitance | Cf | V=0, f=1MHZ | - | 0.4 | - | pF |
| | Response time (Rise)(*3) | tr | Vce=5V, Ic=2mA, RL=100Ω | - | 200 | - | µs |
| | Response time (Fall)(*3) | tf | Vce=5V, Ic=2mA, RL=100Ω | - | 200 | - | µs |

*3 Test circuit for switching time

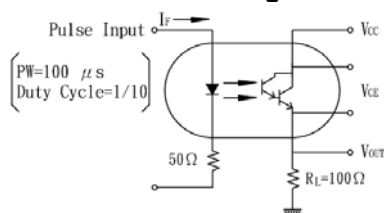


Fig.1 Current Transfer Ratio vs. Forward Current

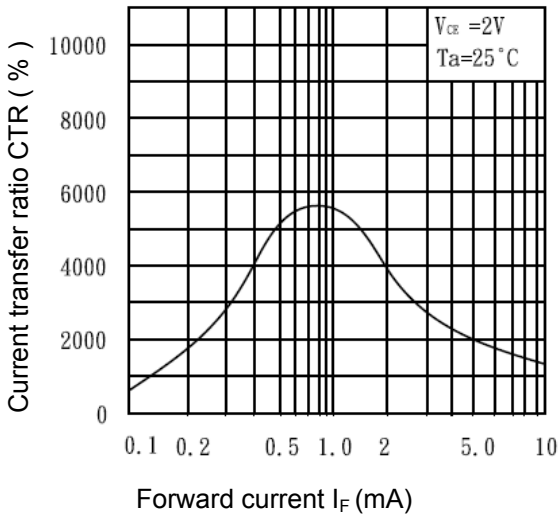


Fig.2 Forward Current vs. Ambient Temperature

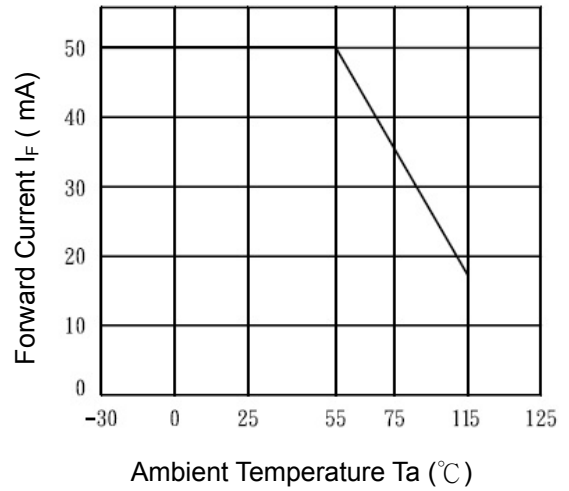


Fig.3 Collector Power Dissipation vs. Ambient Temperature

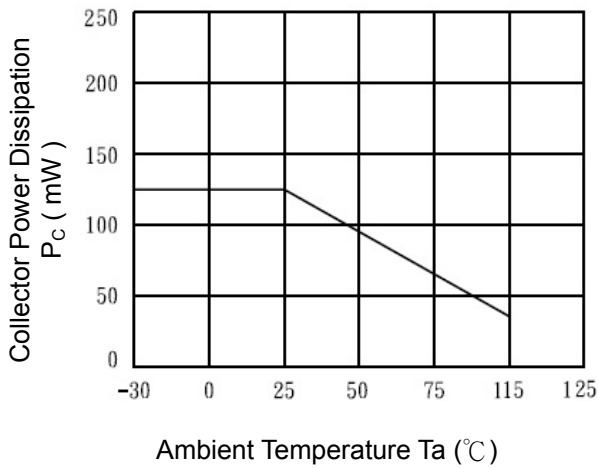


Fig.4 Forward Current vs. Forward Voltage

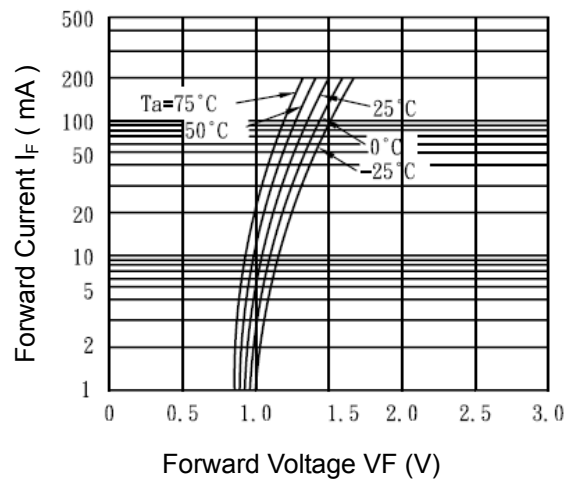


Fig.5 Collector Current vs. Collector-Emitter Voltage

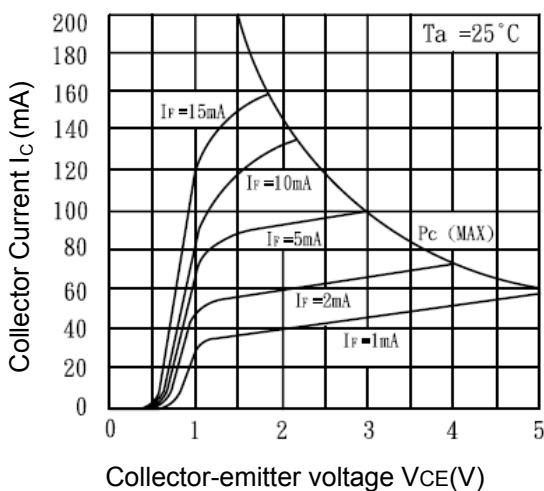
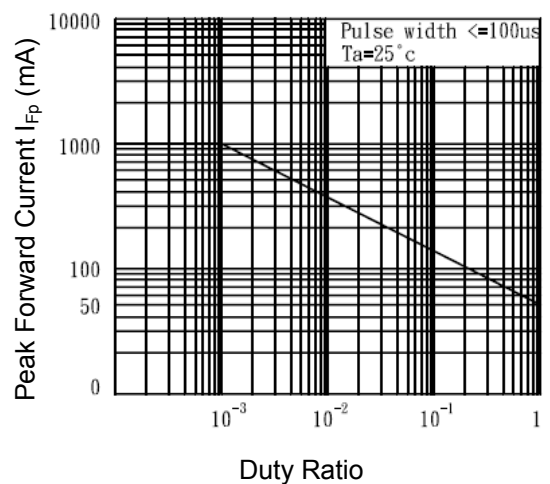


Fig.6 Peak Forward Current vs. Duty Ratio



Collector-Emitter Saturation

Fig.7 Voltage vs. Ambient Temperature

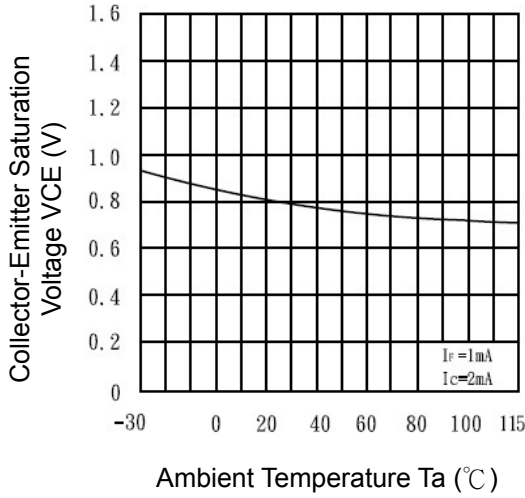


Fig.8 Collector Dark Current vs. Ambient Temperature

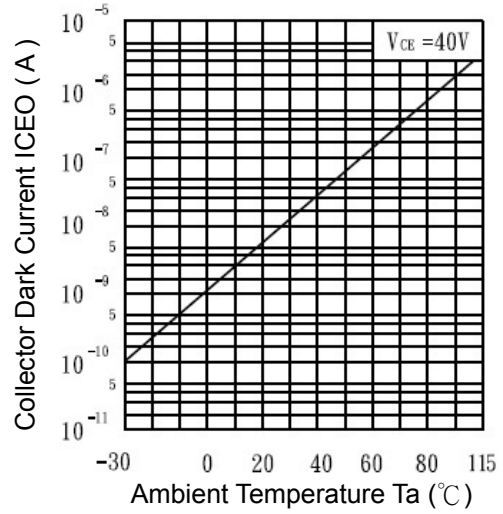


Fig.9 Response Time vs. Load Resistance

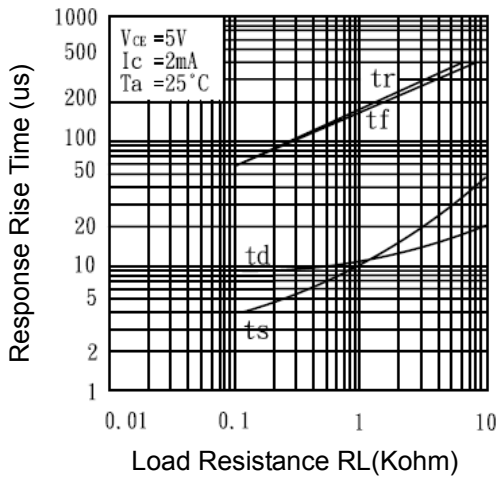
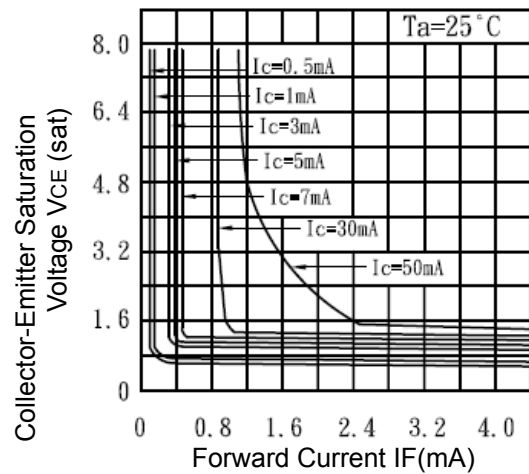
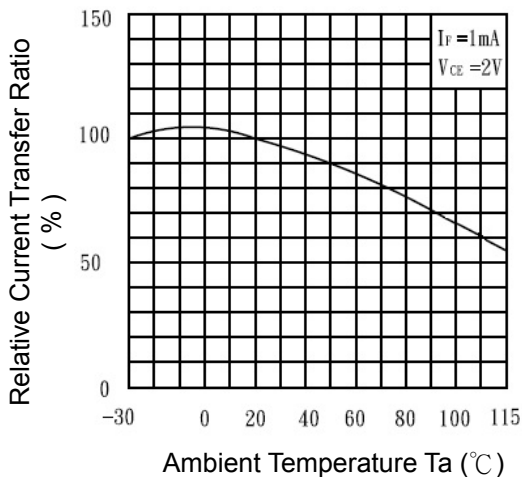


Fig.10 Collector-Emitter Saturation Voltage vs. Forward Current



Relative Current Transfer

Fig.11 Ratio vs. Ambient Temperature



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